



NTLJD4116NT1G Information



For Reference Only

Part Number NTLJD4116NT1G
Manufacturer ON Semiconductor

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 30V 2.5A 6-WDFN

Package 6-WDFN Exposed Pad

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









NTLJD4116NT1G Specifications

Manufacturer Part Number	NTLJD4116NT1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	6-WDFN Exposed Pad
Series	-
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	2.5A
Rds On (Max) @ Id, Vgs	70 mOhm @ 2A, 4.5V
Vgs(th) (Max) @ Id	1V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	6.5nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	427pF @ 15V
Power - Max	710mW
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	6-WDFN Exposed Pad
Supplier Device Package	6-WDFN (2x2)
	Report errors?

NTLJD4116NT1G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NTLJD4116NT1G Payment Methods



















NTLJD4116NT1G Shipping Methods













If you have any question about NTLJD4116NT1G, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com